

# TK7J90E

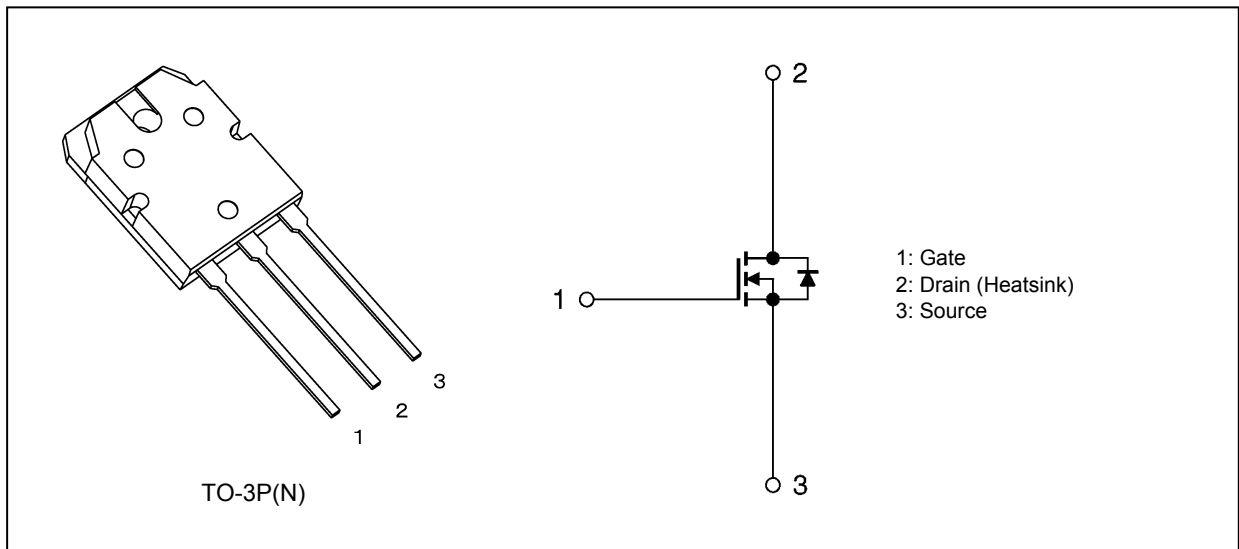
## 1. Applications

- Switching Voltage Regulators

## 2. Features

- (1) Low drain-source on-resistance:  $R_{DS(ON)} = 1.6 \Omega$  (typ.)
- (2) Low leakage current :  $I_{DSS} = 10 \mu\text{A}$  (max) ( $V_{DS} = 720 \text{ V}$ )
- (3) Enhancement mode:  $V_{th} = 2.5$  to  $4.0 \text{ V}$  ( $V_{DS} = 10 \text{ V}$ ,  $I_D = 0.7 \text{ mA}$ )

## 3. Packaging and Internal Circuit



Start of commercial production

2013-12

**4. Absolute Maximum Ratings (Note) ( $T_a = 25\text{ }^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Rating	Unit
Drain-source voltage	$V_{DSS}$	900	V
Gate-source voltage	$V_{GSS}$	$\pm 30$	
Drain current (DC) (Note 1)	$I_D$	7	A
Drain current (pulsed) (Note 1)	$I_{DP}$	21	
Power dissipation ( $T_c = 25^\circ\text{C}$ )	$P_D$	200	W
Single-pulse avalanche energy (Note 2)	$E_{AS}$	235	mJ
Avalanche current	$I_{AR}$	7	A
Reverse drain current (DC) (Note 1)	$I_{DR}$	7	
Reverse drain current (pulsed) (Note 1)	$I_{DRP}$	21	
Channel temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage temperature	$T_{stg}$	-55 to 150	
Mounting torque	TOR	0.8	N · m

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

**5. Thermal Characteristics**

Characteristics	Symbol	Max	Unit
Channel-to-case thermal resistance	$R_{th(ch-c)}$	0.625	$^\circ\text{C}/\text{W}$
Channel-to-ambient thermal resistance	$R_{th(ch-a)}$	50	$^\circ\text{C}/\text{W}$

Note 1: Ensure that the channel temperature does not exceed  $150\text{ }^\circ\text{C}$ .

Note 2:  $V_{DD} = 90\text{ V}$ ,  $T_{ch} = 25^\circ\text{C}$  (initial),  $L = 8.8\text{ mH}$ ,  $R_G = 25\ \Omega$ ,  $I_{AR} = 7\text{ A}$

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

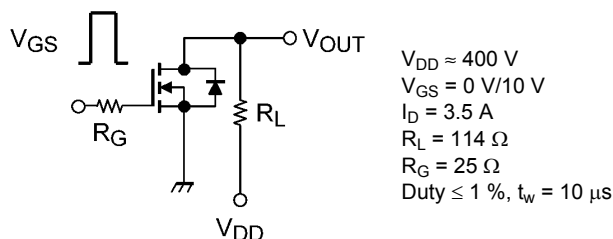
**6. Electrical Characteristics**

**6.1. Static Characteristics ( $T_a = 25\text{ }^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	$I_{GSS}$	$V_{GS} = \pm 30\text{ V}, V_{DS} = 0\text{ V}$	—	—	$\pm 1$	$\mu\text{A}$
Drain cut-off current	$I_{DSS}$	$V_{DS} = 720\text{ V}, V_{GS} = 0\text{ V}$	—	—	10	
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10\text{ mA}, V_{GS} = 0\text{ V}$	900	—	—	V
Gate threshold voltage	$V_{th}$	$V_{DS} = 10\text{ V}, I_D = 0.7\text{ mA}$	2.5	—	4.0	
Drain-source on-resistance	$R_{DS(ON)}$	$V_{GS} = 10\text{ V}, I_D = 3.5\text{ A}$	—	1.6	2.0	$\Omega$

**6.2. Dynamic Characteristics ( $T_a = 25\text{ }^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Input capacitance	$C_{iss}$	$V_{DS} = 25\text{ V}, V_{GS} = 0\text{ V}, f = 1\text{ MHz}$	—	1350	—	$\text{pF}$
Reverse transfer capacitance	$C_{rss}$		—	10	—	
Output capacitance	$C_{oss}$		—	110	—	
Gate resistance	$r_g$	$V_{DS} = \text{OPEN}, f = 1\text{ MHz}$	—	4.0	—	$\Omega$
Switching time (rise time)	$t_r$	See Fig. 6.2.1.	—	20	—	ns
Switching time (turn-on time)	$t_{on}$		—	55	—	
Switching time (fall time)	$t_f$		—	15	—	
Switching time (turn-off time)	$t_{off}$		—	85	—	
MOSFET dv/dt ruggedness	dv/dt	$V_{DD} = 0\text{ to }400\text{ V}, I_D = 7\text{ A}$	20	—	—	V/ns



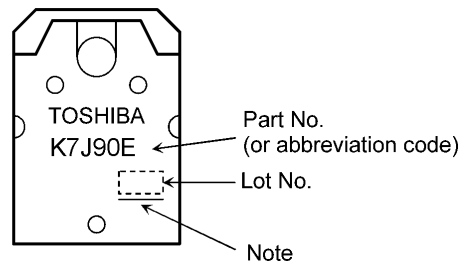
**Fig. 6.2.1 Switching Time Test Circuit**

**6.3. Gate Charge Characteristics ( $T_a = 25\text{ }^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Total gate charge (gate-source plus gate-drain)	$Q_g$	$V_{DD} \approx 400\text{ V}, V_{GS} = 10\text{ V}, I_D = 7\text{ A}$	—	32	—	nC
Gate-source charge 1	$Q_{gs1}$		—	10	—	
Gate-drain charge	$Q_{gd}$		—	12	—	

**6.4. Source-Drain Characteristics ( $T_a = 25\text{ }^\circ\text{C}$  unless otherwise specified)**

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Diode forward voltage	$V_{DSF}$	$I_{DR} = 7\text{ A}, V_{GS} = 0\text{ V}$	—	—	-1.7	V
Reverse recovery time	$t_{rr}$	$I_{DR} = 7\text{ A}, V_{GS} = 0\text{ V}$ $-di_{DR}/dt = 100\text{ A}/\mu\text{s}$	—	1100	—	ns
Reverse recovery charge	$Q_{rr}$		—	8	—	$\mu\text{C}$
Peak reverse recovery current	$I_{rr}$		—	18	—	A

**7. Marking (Note)****Fig. 7.1 Marking**

Note: A line under a Lot No. identifies the indication of product Labels.

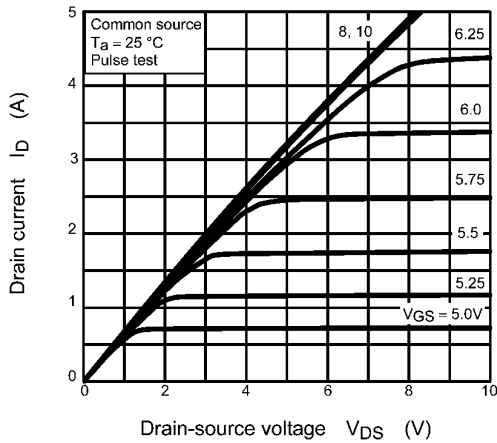
Not underlined: [[Pb]]/INCLUDES > MCV

Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

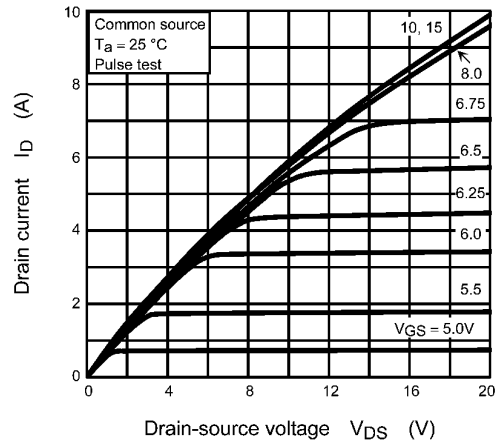
Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product.

The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

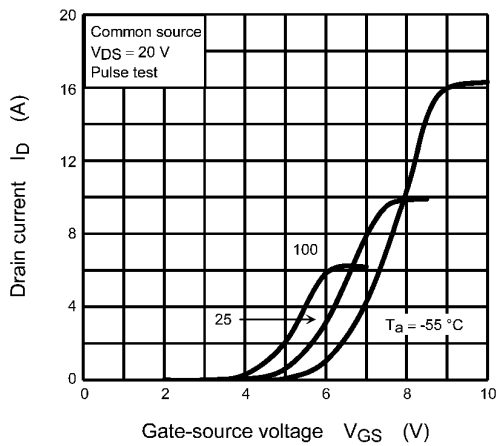
**8. Characteristics Curves (Note)**



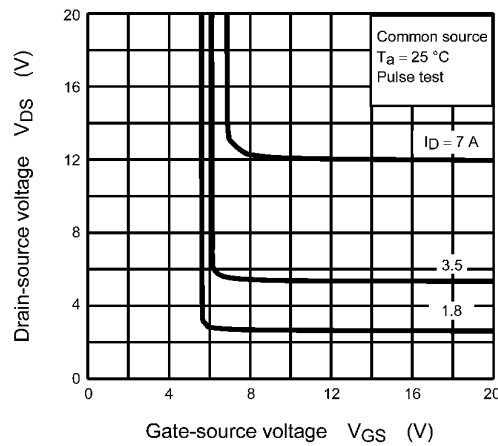
**Fig. 8.1  $I_D - V_{DS}$**



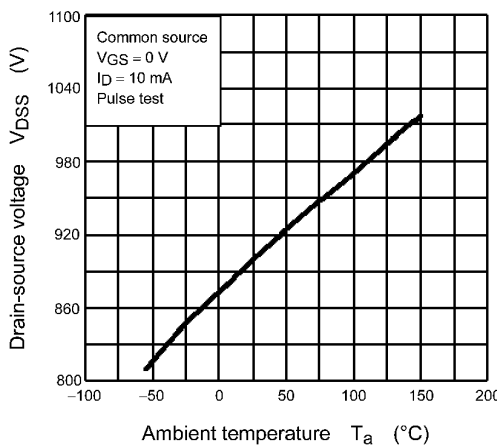
**Fig. 8.2  $I_D - V_{DS}$**



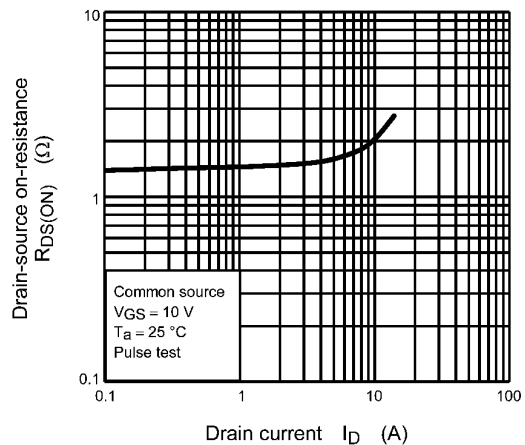
**Fig. 8.3  $I_D - V_{GS}$**



**Fig. 8.4  $V_{DS} - V_{GS}$**



**Fig. 8.5  $V_{DSS} - T_a$**



**Fig. 8.6  $R_{DS(ON)} - I_D$**

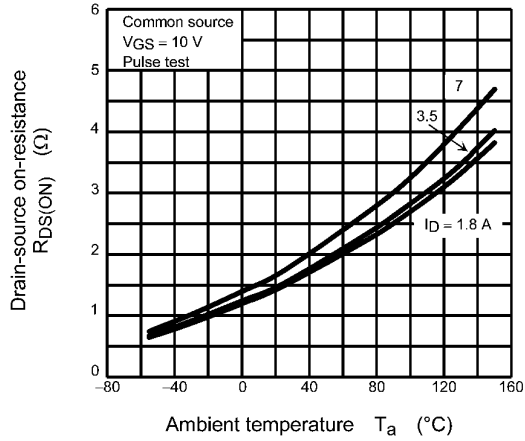


Fig. 8.7  $R_{DS(ON)} - T_a$

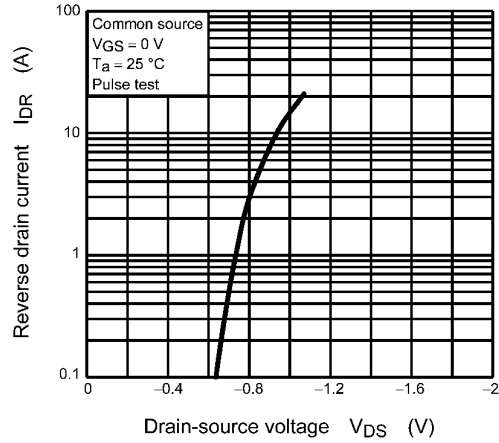


Fig. 8.8  $I_{DR} - V_{DS}$

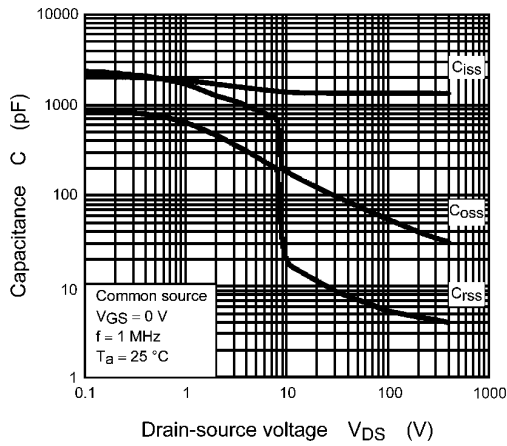


Fig. 8.9  $C - V_{DS}$

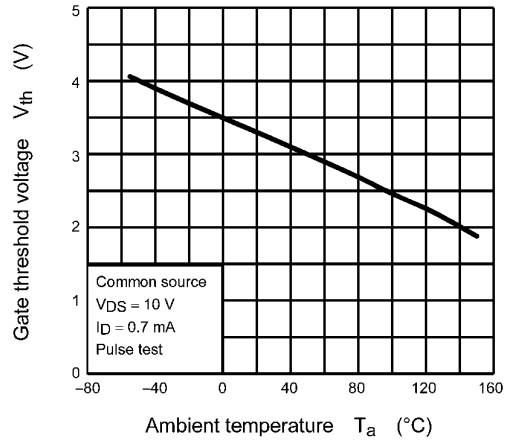


Fig. 8.10  $V_{th} - T_a$

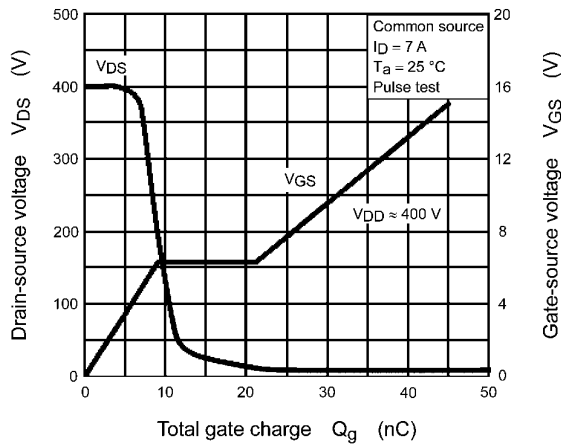


Fig. 8.11 Dynamic Input/Output Characteristics

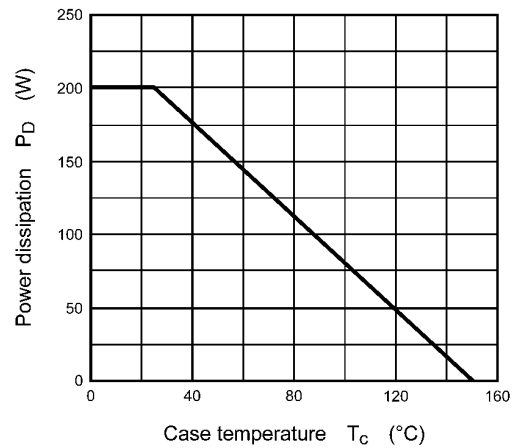
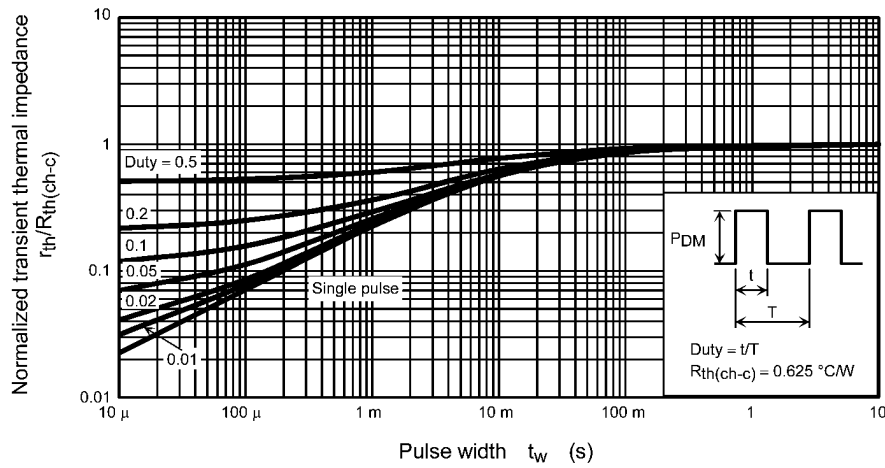
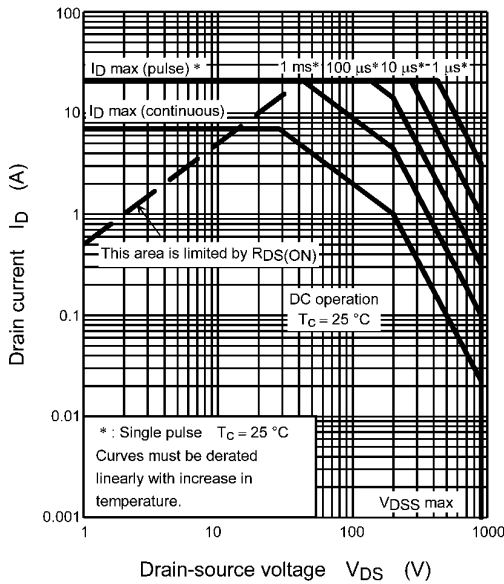


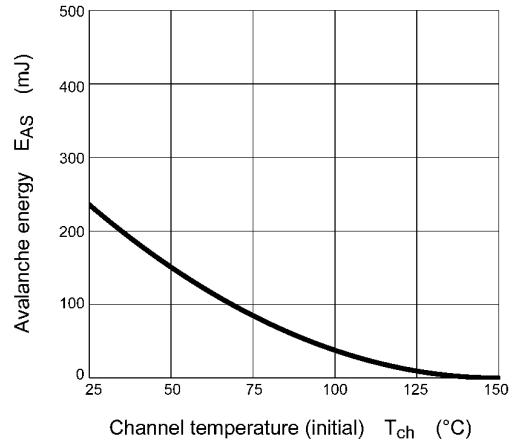
Fig. 8.12  $P_D - T_c$   
(Guaranteed Maximum)



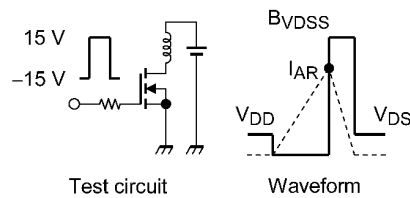
**Fig. 8.13  $r_{th} - t_w$**   
(Guaranteed Maximum)



**Fig. 8.14 Safe Operating Area**  
(Guaranteed Maximum)



**Fig. 8.15  $E_{AS} - T_{ch}$**   
(Guaranteed Maximum)



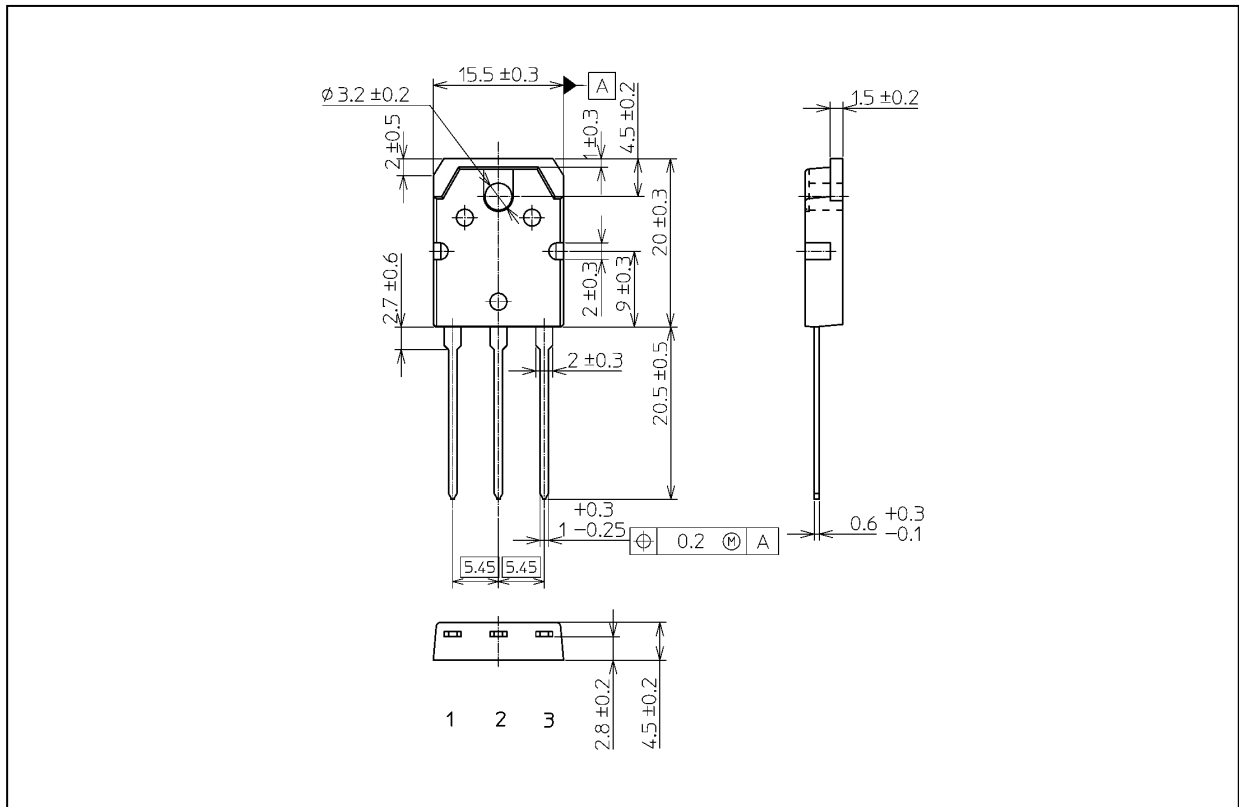
$$R_G = 25 \Omega, V_{DD} = 90 \text{ V } E_{AS} = \frac{1}{2} \cdot L \cdot I_{AR}^2 \cdot \left[ \frac{BV_{DS}}{BV_{DS} - V_{DD}} \right]$$

**Fig. 8.16 Test Circuit/Waveform**

Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

**Package Dimensions**

Unit: mm



Weight: 4.6 g (typ.)

Package Name(s)
JEITA: SC-65
TOSHIBA: 2-16C1S
Nickname: TO-3P(N)



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